

WHAT IS CLAIMED IS:

- 1 1. A method of forming an optical waveguide on an undercladding
2 layer of a substrate, the method comprising:
3 forming at least one silicate glass optical core on said undercladding
4 layer using a high-density plasma deposition process including a silicon source gas and
5 an oxygen source gas;
6 wherein the refractive index of the undercladding layer is less than the
7 refractive index of the optical core.
- 1 2. The method of claim 1 wherein the high-density plasma process
2 comprises pressure of less than 100 millitorr and an RF energy greater than 3
3 Watts/cm².
- 1 3. The method of claim 2 wherein the high-density plasma process
2 further comprises a nitrogen source gas and the optical core comprises silicon, oxygen,
3 and nitrogen.
- 1 4. The method of claim 3 wherein the nitrogen source gas is
2 molecular nitrogen.
- 1 5. The method of claim 3 wherein the optical core is an SiON
2 optical core.
- 1 6. The method of claim 3 wherein the ratio of oxygen atoms to
2 silicon atoms is greater than 3:1.
- 1 7. The method of claim 3 wherein the silicon source comprises
2 silane, the oxygen source comprises molecular oxygen, and the nitrogen source
3 comprises molecular nitrogen.
- 1 8. The method of claim 7 wherein the ratio of molecular oxygen to
2 silane is greater than 1.5:1.
- 1 9. The method of claim 7 wherein the oxygen source flow is
2 between 200-600 sccm.

1 10. The method of claim 7 wherein the ratio of molecular nitrogen to
2 silane is between 0.5 and 5.0.

1 11. The method of claim 7 wherein the nitrogen source flow is
2 between 300-500 sccm.

1 12. The method of claim 1 wherein the high-density plasma process
2 is carried out at a temperature of greater than 600°C.

1 13. The method of claim 1 wherein the optical core comprises a
2 phosphorus doped silicate glass or germanium doped silicate glass.

1 14. The method of claim 1 wherein the contrast between the
2 refractive index of the core and the refractive index of the undercladding layer is
3 greater than 2%.

1 15. The method of claim 1 wherein forming at least one optical core
2 comprises:
3 depositing a continuous optical core layer using said high-density
4 plasma deposition process; and
5 etching the continuous optical core layer to form the at least one optical
6 core.

1 16. The method of claim 15 wherein the depositing using said high-
2 density plasma deposition process does not use an RF bias.

1 17. The method of claim 1 wherein forming at least one optical core
2 comprises:
3 etching at least one trench in the undercladding layer;
4 depositing the at least one optical core in the corresponding at least one
5 trench using said high-density plasma deposition process; and
6 depositing an uppercladding layer over the at least one optical core.

1 18. The method of claim 17 wherein the depositing using said high-
2 density plasma deposition process does includes an RF bias.

1 21. The method of claim 1 further comprising annealing the at least
2 one optical core after the high-density plasma deposition process.

1 22. A method of depositing an optical core on a substrate in a
2 processing chamber comprising:

3 establishing a pressure of less than 100 millitorr in said processing
4 chamber;

5 generating an RF power density of greater than 3 Watts/cm²; and
6 providing a silicon source gas, an oxygen source gas, and a dopant
7 source gas in said processing chamber, wherein the dopant source gas increases the
8 refractive index of said optical core above 1.46.

1 23. The method of claim 22 wherein the ratio of oxygen atoms to
2 silicon atoms is greater than 3:1.

1 25. The method of claim 24 wherein said nitrogen source gas is
2 molecular nitrogen.

26. The method of claim 25 wherein the silicon source gas is silane.

1 29. A substrate processing system comprising:
2 a housing defining a process chamber;

1 30 . . . The substrate processing system of claim 29 wherein the ratio of
2 oxygen atoms to silicon atoms is greater than 3:1.

1 31. The substrate processing system of claim 29 wherein the dopant-
2 containing gas comprises a nitrogen-containing gas and the optical core comprises
3 silicon, oxygen, and nitrogen.

1 33. The substrate processing system of claim 32 wherein the ratio of
2 molecular nitrogen to silane is between 0.5 and 5.0.

1 34. The substrate processing system of claim 29 wherein the
2 substrate holder comprises an electrostatic chuck, and wherein computer-readable
3 program further includes instructions for turning electrostatic chuck off during
4 deposition of the silicate glass optical core.

1 35. The substrate processing system of claim 29 further comprising a
2 top RF source and a side RF source, wherein the ratio of power of the top RF source to
3 the side RF source is between 0.21 and 0.73.

1 36. The substrate processing system of claim 29 wherein the dopant
2 containing gas is a phosphorus containing gas or germanium containing gas.

1 37. A computer-readable storage medium having a computer-
2 readable program embodied therein for directing operation of a substrate processing
3 system including a process chamber; a plasma generation system; and a gas delivery
4 system configured to introduce gases into the process chamber, the computer-readable
5 program including instructions for operating the substrate processing system to form an
6 optical core on a substrate disposed in the processing chamber in accordance with the
7 following:

8 establishing a pressure of less than 100 millitorr in said processing
9 chamber;

10 generating an RF power density of greater than 3 Watts/cm²; and
11 providing a silicon source gas, an oxygen source gas, and a dopant
12 source gas in said processing chamber, wherein the dopant source gas increases the
13 refractive index of said optical core above 1.46.

1 38. The computer-readable storage medium of claim 37 wherein the
2 ratio of oxygen atoms to silicon atoms is greater than 3:1.

1 39. The computer-readable storage medium of claim 37 wherein the
2 dopant source gas is a nitrogen source gas and the optical core comprises silicon,
3 oxygen, and nitrogen.

1 41. The computer-readable storage medium of claim 40 wherein the
2 ratio of molecular nitrogen to silane is between 0.5 and 5.0.